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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Active
Core Processor	ARM® Cortex®-A9
Number of Cores/Bus Width	2 Core, 32-Bit
Speed	1.2GHz
Co-Processors/DSP	Multimedia; NEON™ SIMD
RAM Controllers	LPDDR2, LVDDR3, DDR3
Graphics Acceleration	Yes
Display & Interface Controllers	Keypad, LCD
Ethernet	10/100/1000Mbps (1)
SATA	SATA 3Gbps (1)
USB	USB 2.0 + PHY (4)
Voltage - I/O	1.8V, 2.5V, 2.8V, 3.3V
Operating Temperature	-20°C ~ 105°C (TJ)
Security Features	ARM TZ, Boot Security, Cryptography, RTIC, Secure Fusebox, Secure JTAG, Secure Memory, Secure RTC, Tamper Detection
Package / Case	624-LFBGA, FCBGA
Supplier Device Package	624-FCPBGA (21x21)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mcimx6d5eym12ce

Table 1. Example Orderable Part Numbers (continued)

Part Number	Quad/Dual CPU	Options	Speed[1] Grade	Temperature Grade	Package
SCIMX6Q5EYM12CE	i.MX 6Quad	Includes VPU, GPU, HCP	1.2 GHz	Extended Commercial	21 mm x 21 mm, 0.8 mm pitch, FCPBGA (non-lidded)
MCIMX6D5EYM12AC	i.MX 6Dual	Includes VPU, GPU	1.2 GHz	Extended Commercial	21 mm x 21 mm, 0.8 mm pitch, FCPBGA (non-lidded)
MCIMX6D5EYM12AD	i.MX 6Dual	Includes VPU, GPU	1.2 GHz	Extended Commercial	21 mm x 21 mm, 0.8 mm pitch, FCPBGA (non-lidded)
MCIMX6D5EYM12AE	i.MX 6Dual	Includes VPU, GPU	1.2 GHz	Extended Commercial	21 mm x 21 mm, 0.8 mm pitch, FCPBGA (non-lidded)
SCIMX6D5EYM12CC	i.MX 6Dual	Includes VPU, GPU, HCP	1.2 GHz	Extended Commercial	21 mm x 21 mm, 0.8 mm pitch, FCPBGA (non-lidded)
SCIMX6D5EYM12CD	i.MX 6Dual	Includes VPU, GPU, HCP	1.2 GHz	Extended Commercial	21 mm x 21 mm, 0.8 mm pitch, FCPBGA (non-lidded)
SCIMX6D5EYM12CE	i.MX 6Dual	Includes VPU, GPU, HCP	1.2 GHz	Extended Commercial	21 mm x 21 mm, 0.8 mm pitch, FCPBGA (non-lidded)

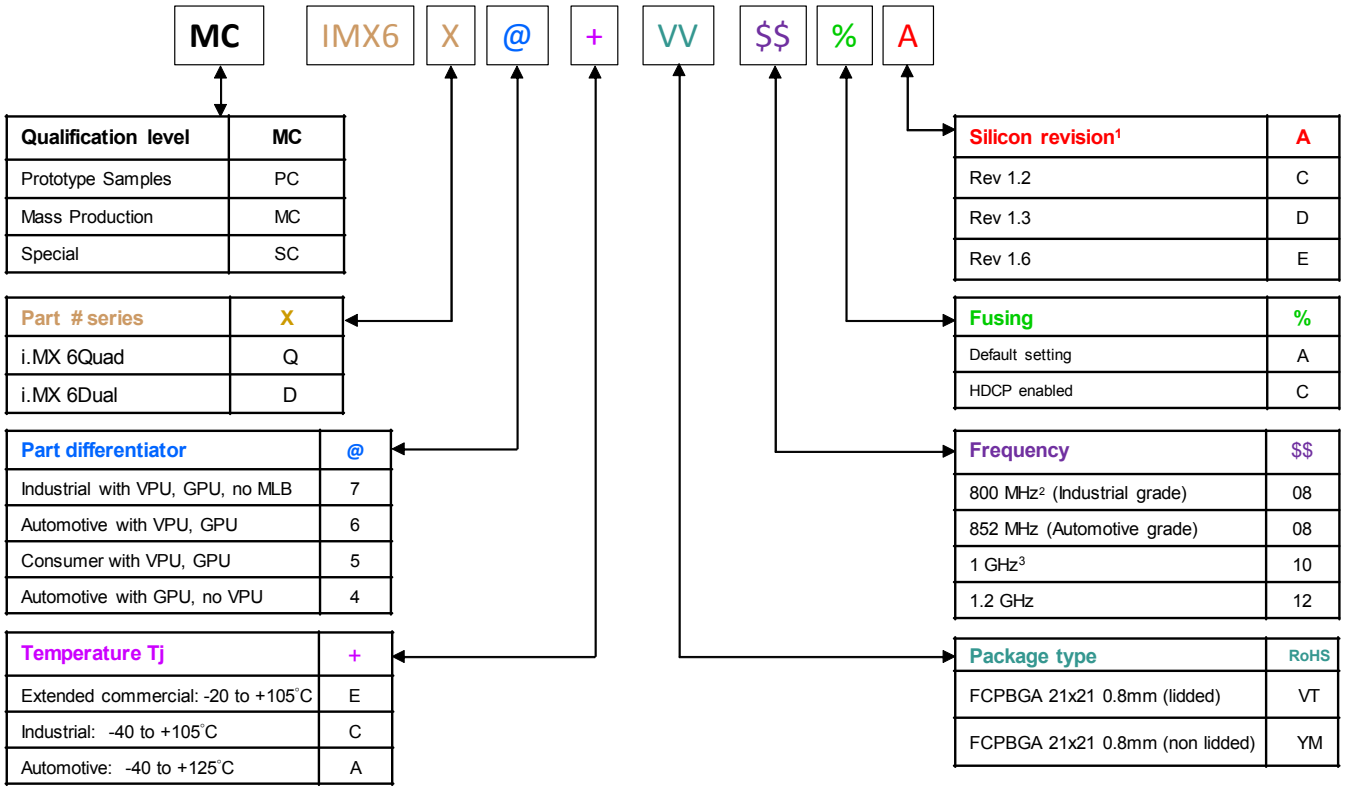
[1] If a 24 MHz input clock is used (required for USB), the maximum SoC speed is limited to 996 MHz.

Figure 1 describes the part number nomenclature to identify the characteristics of the specific part number you have (for example, cores, frequency, temperature grade, fuse options, silicon revision). Figure 1 applies to the i.MX 6Dual/6Quad.

The two characteristics that identify which data sheet a specific part applies to are the part number series field and the temperature grade (junction) field:

- The i.MX 6Dual/6Quad Automotive and Infotainment Applications Processors data sheet (IMX6DQAEC) covers parts listed with “A (Automotive temp)”
- The i.MX 6Dual/6Quad Applications Processors for Consumer Products data sheet (IMX6DQCEC) covers parts listed with “D (Commercial temp)” or “E (Extended Commercial temp)”
- The i.MX 6Dual/6Quad Applications Processors for Industrial Products data sheet (IMX6DQIEC) covers parts listed with “C (Industrial temp)”

The Ensure that you have the right data sheet for your specific part by checking the temperature grade (junction) field and matching it to the right data sheet. If you have questions, see nxp.com/imx6series or contact your NXP representative.



1. See the nxp.com\imx6series Web page for latest information on the available silicon revision.
2. If a 24 MHz input clock is used (required for USB), the maximum SoC speed is limited to 792 MHz.
3. If a 24 MHz input clock is used (required for USB), the maximum SoC speed is limited to 996 MHz.

Figure 1. Part Number Nomenclature—i.MX 6Quad and i.MX 6Dual

1.2 Features

The i.MX 6Dual/6Quad processors are based on ARM Cortex-A9 MPCore platform, which has the following features:

- ARM Cortex-A9 MPCore 4xCPU processor (with TrustZone®)
- The core configuration is symmetric, where each core includes:
  - 32 KByte L1 Instruction Cache
  - 32 KByte L1 Data Cache
  - Private Timer and Watchdog
  - Cortex-A9 NEON MPE (Media Processing Engine) Co-processor

The ARM Cortex-A9 MPCore complex includes:

- General Interrupt Controller (GIC) with 128 interrupt support
- Global Timer
- Snoop Control Unit (SCU)
- 1 MB unified I/D L2 cache, shared by two/four cores

The typical values shown in Table 7 are required for use with NXP BSPs to ensure precise time keeping and USB operation. For RTC_XTALI operation, two clock sources are available:

- On-chip 40 kHz ring oscillator: This clock source has the following characteristics:
  - Approximately 25 µA more Idd than crystal oscillator
  - Approximately ±50% tolerance
  - No external component required
  - Starts up quicker than 32 kHz crystal oscillator
- External crystal oscillator with on-chip support circuit
  - At power up, an internal ring oscillator is used. After crystal oscillator is stable, the clock circuit switches over to the crystal oscillator automatically.
  - Higher accuracy than ring oscillator.
  - If no external crystal is present, then the ring oscillator is used.

The decision to choose a clock source should be based on real-time clock use and precision timeout.

4.1.5 Maximum Measured Supply Currents

Power consumption is highly dependent on the application. Estimating the maximum supply currents required for power supply design is difficult because the use case that requires maximum supply current is not a realistic use case.

To help illustrate the effect of the application on power consumption, data was collected while running industry standard benchmarks that are designed to be compute and graphic intensive. The results provided are intended to be used as guidelines for power supply design.

Description of test conditions:

- The Power Virus data shown in Table 8 represent a use case designed specifically to show the maximum current consumption possible for the ARM core complex. All cores are running at the defined maximum frequency and are limited to L1 cache accesses only to ensure no pipeline stalls. Although a valid condition, it would have a very limited, if any, practical use case, and be limited to an extremely low duty cycle unless the intention was to specifically cause the worst case power consumption.
- EEMBC CoreMark: Benchmark designed specifically for the purpose of measuring the performance of a CPU core. More information available at www.eembc.org/coremark. Note that this benchmark is designed as a core performance benchmark, not a power benchmark. This use case is provided as an example of power consumption that would be typical in a computationally-intensive application rather than the Power Virus.
- 3DMark Mobile 2011: Suite of benchmarks designed for the purpose of measuring graphics and overall system performance. More information available at www.rightware.com/benchmarks. Note that this benchmark is designed as a graphics performance benchmark, not a power benchmark. This use case is provided as an example of power consumption that would be typical in a very graphics-intensive application.
- Devices used for the tests were from the high current end of the expected process variation.

The NXP power management IC, MMPF0100xxxx, which is targeted for the i.MX 6 series processor family, supports the power consumption shown in Table 8, however a robust thermal design is required for the increased system power dissipation.

See the *i.MX 6Dual/6Quad Power Consumption Measurement Application Note* (AN4509) for more details on typical power consumption under various use case definitions.

Table 8. Maximum Supply Currents

Power Supply	Conditions	Maximum Current		Unit
		Power Virus	CoreMark	
i.MX 6Quad: VDD_ARM_IN + VDD_ARM23_IN	• ARM frequency = 996 MHz • ARM LDOs set to 1.3V • T_j = 105°C	3730	2370	mA
i.MX 6Dual: VDD_ARM_IN	• ARM frequency = 996 MHz • ARM LDOs set to 1.3V • T_j = 105°C	2230	1420	mA
i.MX 6Dual or i.MX 6Quad: VDD_SOC_IN	• Running 3DMark • GPU frequency = 600 MHz • SOC LDO set to 1.3V • T_j = 105°C	2370		mA
VDD_HIGH_IN	—	125[1]		mA
VDD_SNVS_IN	—	275[2]		µA
USB_OTG_VBUS/ USB_H1_VBUS (LDO 3P0)	—	25[3]		mA
Primary Interface (IO) Supplies				
NVCC_DRAM	—	(see note[4])		
NVCC_ENET	N=10	Use maximum IO equation[5]		
NVCC_LCD	N=29	Use maximum IO equation[5]		
NVCC_GPIO	N=24	Use maximum IO equation[5]		
NVCC_CSI	N=20	Use maximum IO equation[5]		
NVCC_EIM0	N=19	Use maximum IO equation[5]		
NVCC_EIM1	N=14	Use maximum IO equation[5]		
NVCC_EIM2	N=20	Use maximum IO equation[5]		
NVCC_JTAG	N=6	Use maximum IO equation[5]		
NVCC_RGMII	N=6	Use maximum IO equation[5]		
NVCC_SD1	N=6	Use maximum IO equation[5]		
NVCC_SD2	N=6	Use maximum IO equation[5]		
NVCC_SD3	N=11	Use maximum IO equation[5]		
NVCC_NANDF	N=26	Use maximum IO equation[5]		
NVCC_MIPI	—	25.5		mA

Table 8. Maximum Supply Currents (continued)

Power Supply	Conditions	Maximum Current		Unit
		Power Virus	CoreMark	
NVCC_LVDS2P5	—	NVCC_LVDS2P5 is connected to VDD_HIGH_CAP at the board level. VDD_HIGH_CAP is capable of handing the current required by NVCC_LVDS2P5.		
MISC				
DRAM_VREF	—	1		mA

1 The actual maximum current drawn from VDD_HIGH_IN will be as shown plus any additional current drawn from the VDD_HIGH_CAP outputs, depending upon actual application configuration (for example, NVCC_LVDS_2P5, NVCC_MIPI, or HDMI, PCIe, and SATA VPH supplies).

2 Under normal operating conditions, the maximum current on VDD_SNVS_IN is shown Table 8. The maximum VDD_SNVS_IN current may be higher depending on specific operating configurations, such as BOOT_MODE[1:0] not equal to 00, or use of the Tamper feature. During initial power on, VDD_SNVS_IN can draw up to 1 mA if the supply is capable of sourcing that current. If less than 1 mA is available, the VDD_SNVS_CAP charge time will increase.

3 This is the maximum current per active USB physical interface.

4 The DRAM power consumption is dependent on several factors such as external signal termination. DRAM power calculators are typically available from memory vendors which take into account factors such as signal termination.
See the *i.MX 6Dual/6Quad Power Consumption Measurement Application Note* (AN4509) for examples of DRAM power consumption during specific use case scenarios.

5 General equation for estimated, maximum power consumption of an IO power supply:
Imax = N x C x V x (0.5 x F)
Where:
N—Number of IO pins supplied by the power line
C—Equivalent external capacitive load
V—IO voltage
(0.5 xF)—Data change rate. Up to 0.5 of the clock rate (F)
In this equation, Imax is in Amps, C in Farads, V in Volts, and F in Hertz.

4.1.6 Low Power Mode Supply Currents

Table 9 shows the current core consumption (not including I/O) of the i.MX 6Dual/6Quad processors in selected low power modes.

Table 9. Stop Mode Current and Power Consumption

Mode	Test Conditions	Supply	Typical[1]	Unit
WAIT	• ARM, SoC, and PU LDOs are set to 1.225 V • HIGH LDO set to 2.5 V • Clocks are gated • DDR is in self refresh • PLLs are active in bypass (24 MHz) • Supply voltages remain ON	VDD_ARM_IN (1.4 V)	6	mA
		VDD_SOC_IN (1.4 V)	23	mA
		VDD_HIGH_IN (3.0 V)	3.7	mA
		Total	52	mW

Table 11. SATA PHY Current Drain (continued)

Mode	Test Conditions	Supply	Typical Current	Unit
P1: Transmitter idle, Rx powered down, LOS disabled	Single Transceiver	SATA_VP	0.67	mA
		SATA_VPH	0.23	
	Clock Module	SATA_VP	6.9	
		SATA_VPH	6.2	
P2: Powered-down state, only LOS and POR enabled	Single Transceiver	SATA_VP	0.53	mA
		SATA_VPH	0.11	
	Clock Module	SATA_VP	0.036	
		SATA_VPH	0.12	
PDDQ mode[3]	Single Transceiver	SATA_VP	0.13	mA
		SATA_VPH	0.012	
	Clock Module	SATA_VP	0.008	
		SATA_VPH	0.004	

1 Programmed for 1.0 V peak-to-peak Tx level.

2 Programmed for 0.9 V peak-to-peak Tx level with no boost or attenuation.

3 LOW power non-functional.

4.1.9 PCIe 2.0 Maximum Power Consumption

Table 12 provides PCIe PHY currents for certain operating modes.

Table 12. PCIe PHY Current Drain

Mode	Test Conditions	Supply	Max Current	Unit
P0: Normal Operation	5G Operations	PCIE_VP (1.1 V)	40	mA
		PCIE_VPTX (1.1 V)	20	
		PCIE_VPH (2.5 V)	21	
	2.5G Operations	PCIE_VP (1.1 V)	27	
		PCIE_VPTX (1.1 V)	20	
		PCIE_VPH (2.5 V)	20	
P0s: Low Recovery Time Latency, Power Saving State	5G Operations	PCIE_VP (1.1 V)	30	mA
		PCIE_VPTX (1.1 V)	2.4	
		PCIE_VPH (2.5 V)	18	
	2.5G Operations	PCIE_VP (1.1 V)	20	
		PCIE_VPTX (1.1 V)	2.4	
		PCIE_VPH (2.5 V)	18	

4.2 Power Supplies Requirements and Restrictions

The system design must comply with power-up sequence, power-down sequence, and steady state guidelines as described in this section to ensure the reliable operation of the device. Any deviation from these sequences may result in the following situations:

- Excessive current during power-up phase
- Prevention of the device from booting
- Irreversible damage to the processor

4.2.1 Power-Up Sequence

For power-up sequence, the restrictions are as follows:

- VDD_SNVS_IN supply must be turned ON before any other power supply. It may be connected (shorted) with VDD_HIGH_IN supply.
- If a coin cell is used to power VDD_SNVS_IN, then ensure that it is connected before any other supply is switched on.
- The SRC_POR_B signal controls the processor POR and must be immediately asserted at power-up and remain asserted until the VDD_ARM_CAP, VDD_SOC_CAP, and VDD_PU_CAP supplies are stable. VDD_ARM_IN and VDD_SOC_IN may be applied in either order with no restrictions.

  Ensure that there is no back voltage (leakage) from any supply on the board towards the 3.3 V supply (for example, from the external components that use both the 1.8 V and 3.3 V supplies).

  NOTE

  USB_OTG_VBUS and USB_H1_VBUS are not part of the power supply sequence and can be powered at any time.

4.2.2 Power-Down Sequence

There are no special restrictions for i.MX 6Dual/6Quad SoC.

4.2.3 Power Supplies Usage

- All I/O pins must not be externally driven while the I/O power supply for the pin (NVCC_xxx) is OFF. This can cause internal latch-up and malfunctions due to reverse current flows. For information about I/O power supply of each pin, see the “Power Group” column of Table 96, “21 x 21 mm Functional Contact Assignments”.
- When the SATA interface is not used, the SATA_VP and SATA_VPH supplies should be grounded. The input and output supplies for rest of the ports (SATA_REXT, SATA_PHY_RX_N, SATA_PHY_RX_P, and SATA_PHY_TX_N) can remain unconnected. It is recommended not to turn OFF the SATA_VPH supply while the SATA_VP supply is ON, as it may lead to excessive power consumption. If boundary scan test is used, SATA_VP and SATA_VPH must remain powered.

4.4.5 MLB PLL

The MediaLB PLL is necessary in the MediaLB 6-Pin implementation to phase align the internal and external clock edges, effectively tuning out the delay of the differential clock receiver and is also responsible for generating the higher speed internal clock, when the internal-to-external clock ratio is not 1:1.

Table 18. MLB PLL Electrical Parameters

Parameter	Value
Lock time	<1.5 ms

4.4.6 ARM PLL

Table 19. ARM PLL Electrical Parameters

Parameter	Value
Clock output range	650 MHz~1.3 GHz
Reference clock	24 MHz
Lock time	<2250 reference cycles

4.5 On-Chip Oscillators

4.5.1 OSC24M

This block implements an amplifier that when combined with a suitable quartz crystal and external load capacitors implements an oscillator. The oscillator is powered from NVCC_PLL_OUT.

The system crystal oscillator consists of a Pierce-type structure running off the digital supply. A straight forward biased-inverter implementation is used.

4.5.2 OSC32K

This block implements an amplifier that when combined with a suitable quartz crystal and external load capacitors implements a low power oscillator. It also implements a power mux such that it can be powered from either a ~3 V backup battery (VDD_SNVS_IN) or VDD_HIGH_IN such as the oscillator consumes power from VDD_HIGH_IN when that supply is available and transitions to the back up battery when VDD_HIGH_IN is lost.

In addition, if the clock monitor determines that the OSC32K is not present, then the source of the 32 kHz clock will automatically switch to the internal ring oscillator.

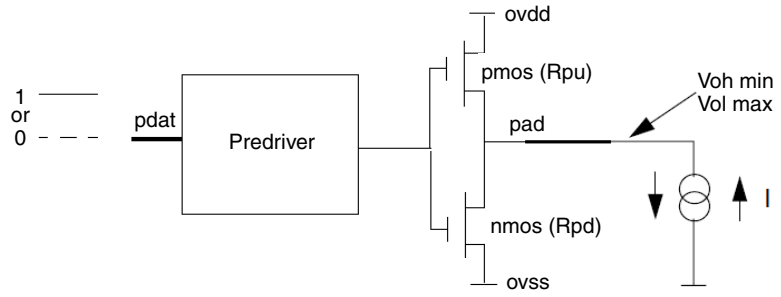


Figure 3. Circuit for Parameters Voh and Vol for I/O Cells

4.6.1 XTALI and RTC_XTALI (Clock Inputs) DC Parameters

Table 21 shows the DC parameters for the clock inputs.

Table 21. XTALI and RTC_XTALI DC Parameters

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
XTALI high-level DC input voltage	Vih	—	0.8 x NVCC_PLL_OUT	—	NVCC_PLL_ OUT	V
XTALI low-level DC input voltage	Vil	—	0	—	0.2	V
RTC_XTALI high-level DC input voltage	Vih	—	0.8	—	1.1 (See note 1)	V
RTC_XTALI low-level DC input voltage	Vil	—	0	—	0.2	V
Input capacitance	C_{IN}	Simulated data	—	5	—	pF
XTALI input leakage current at startup	$I_{XTALI\_STARTUP}$	Power-on startup for 0.15 msec with a driven 32 KHz RTC clock @ 1.1 V. [2]	—	—	600	µA
DC input current	I_{XTALI_DC}	—	—	—	2.5	µA

[1] This voltage specification must not be exceeded and, as such, is an absolute maximum specification.

[2] This current draw is present even if an external clock source directly drives XTALI.

NOTE

The Vil and Vih specifications only apply when an external clock source is used. If a crystal is used, Vil and Vih do not apply.

4.6.2 General Purpose I/O (GPIO) DC Parameters

Table 22 shows DC parameters for GPIO pads. The parameters in Table 22 are guaranteed per the operating ranges in Table 6, unless otherwise noted.

Table 25. DDR3/DDR3L I/O DC Electrical Parameters (continued)

Parameters	Symbol	Test Conditions	Min	Max	Unit
Termination Voltage	Vtt	Vtt tracking OVDD/2	0.49 × OVDD	0.51 × OVDD	V
Input current (no pull-up/down)	Iin	Vin = 0 or OVDD	-2.9	2.9	μA
Pull-up/pull-down impedance mismatch	MMpupd	—	-10	10	%
240 Ω unit calibration resolution	Rres	—	—	10	Ω
Keeper circuit resistance	Rkeep	—	105	175	kΩ

1 OVDD – I/O power supply (1.425 V–1.575 V for DDR3 and 1.283 V–1.45 V for DDR3L).

2 Vref – DDR3/DDR3L external reference voltage.

3 The single-ended signals need to be within the respective limits (Vih(dc) max, Vil(dc) min) for single-ended signals as well as the limitations for overshoot and undershoot (see Table 31).

4.6.5 LVDS I/O DC Parameters

The LVDS interface complies with TIA/EIA 644-A standard. See TIA/EIA STANDARD 644-A, "*Electrical Characteristics of Low Voltage Differential Signaling (LVDS) Interface Circuits*" for details.

Table 26 shows the Low Voltage Differential Signalling (LVDS) I/O DC parameters.

Table 26. LVDS I/O DC Parameters

Parameter	Symbol	Test Conditions	Min	Max	Unit
Output Differential Voltage	V_{OD}	Rload=100 Ω between padP and padN	250	450	mV
Output High Voltage	V_{OH}	I_{OH} = 0 mA	1.25	1.6	V
Output Low Voltage	V_{OL}	I_{OL} = 0 mA	0.9	1.25	
Offset Voltage	V_{OS}	—	1.125	1.375	

4.6.6 MLB 6-Pin I/O DC Parameters

The MLB interface complies with Analog Interface of 6-pin differential Media Local Bus specification version 4.1. See 6-pin differential MLB specification v4.1, "MediaLB 6-pin interface Electrical Characteristics" for details.

NOTE

The MLB 6-pin interface does not support speed mode 8192fs.

Table 27 shows the Media Local Bus (MLB) I/O DC parameters.

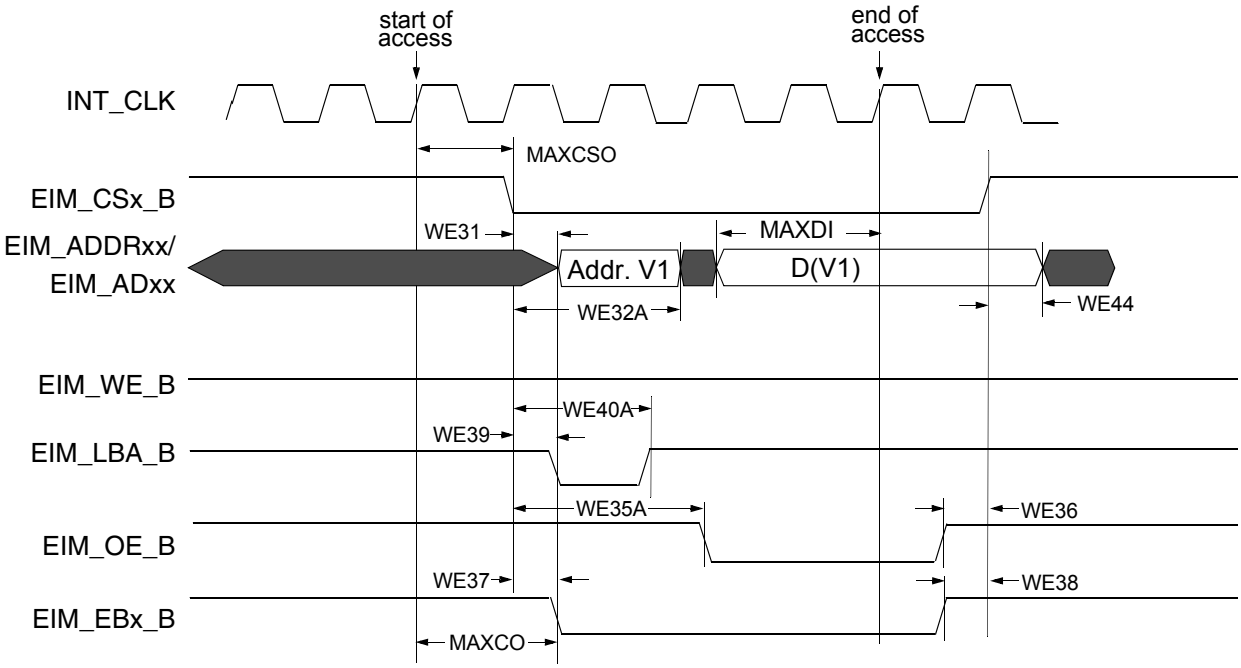


Figure 19. Asynchronous A/D Muxed Read Access (RWSC = 5)

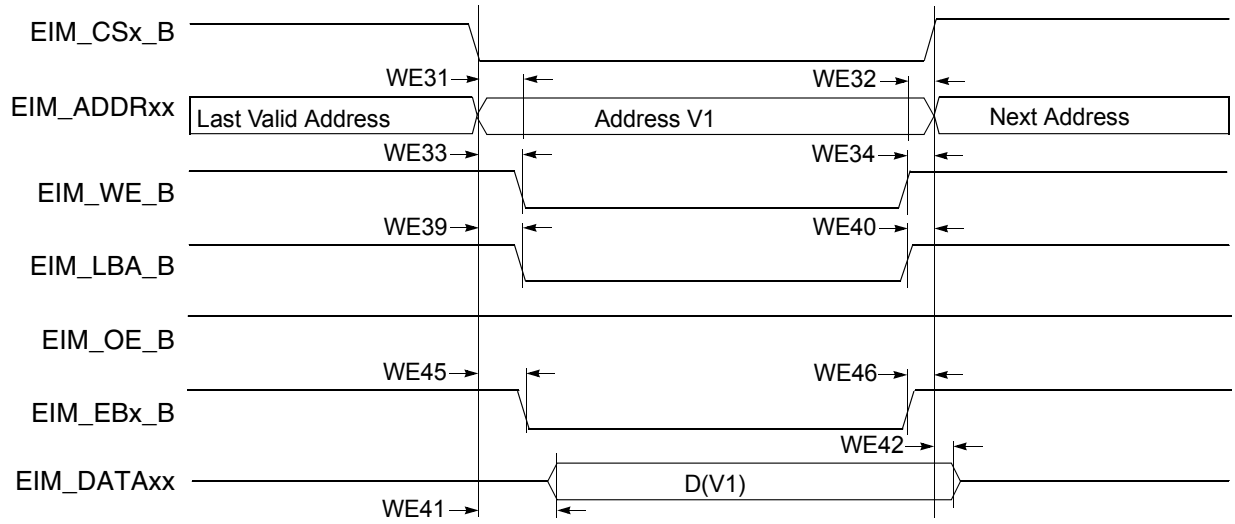


Figure 20. Asynchronous Memory Write Access

[2] In this table:
- t means clock period from axi_clk frequency.
- CSA means register setting for WCSA when in write operations or RCSA when in read operations.
- CSN means register setting for WCSN when in write operations or RCSN when in read operations.
- ADVN means register setting for WADVN when in write operations or RADVN when in read operations.
- ADVA means register setting for WADVA when in write operations or RADVA when in read operations.

4.10 Multi-Mode DDR Controller (MMDC)

The Multi-mode DDR Controller is a dedicated interface to DDR3/DDR3L/LPDDR2 SDRAM.

4.10.1 MMDC Compatibility with JEDEC-Compliant SDRAMs

The i.MX 6Dual/6Quad MMDC supports the following memory types:

- LPDDR2 SDRAM compliant to JESD209-2B LPDDR2 JEDEC standard release June, 2009
- DDR3/DDR3L SDRAM compliant to JESD79-3D DDR3 JEDEC standard release April, 2008

MMDC operation with the standards stated above is contingent upon the board DDR design adherence to the DDR design and layout requirements stated in the *Hardware Development Guide for i.MX 6Quad, 6Dual, 6DualLite, 6Solo Families of Applications Processors* (IMX6DQ6SDLHDG).

4.10.2 MMDC Supported DDR3/DDR3L/LPDDR2 Configurations

The table below shows the supported DDR3/DDR3L/LPDDR2 configurations:

Table 43. i.MX 6Dual/6Quad Supported DDR3/DDR3L/LPDDR2 Configurations

Parameter	LPDDR2	DDR3	DDR3L
Clock frequency	400 MHz	532 MHz	532 MHz
Bus width	32-bit per channel	16/32/64-bit	16/32/64-bit
Channel	Dual	Single	Single
Chip selects	2 per channel	2	2

4.11 General-Purpose Media Interface (GPMI) Timing

The i.MX 6Dual/6Quad GPMI controller is a flexible interface NAND Flash controller with 8-bit data width, up to 200 MB/s I/O speed and individual chip select. It supports Asynchronous timing mode, Source Synchronous timing mode, and Samsung Toggle timing mode separately described in the following subsections.

Table 46. Samsung Toggle Mode Timing Parameters[1] (continued)

ID	Parameter	Symbol	Timing T = GPMI Clock Cycle		Unit
			Min	Max	
NF28	Data write setup	tDS[6]	0.25 × tCK - 0.32	—	ns
NF29	Data write hold	tDH[6]	0.25 × tCK - 0.79	—	ns
NF30	NAND_DQS/NAND_DQ read setup skew	tDQSQ[7]	—	3.18	—
NF31	NAND_DQS/NAND_DQ read hold skew	tQHS[7]	—	3.27	—

1 The GPMI toggle mode output timing can be controlled by the module's internal registers HW_GPMI_TIMING0_ADDRESS_SETUP, HW_GPMI_TIMING0_DATA_SETUP, and HW_GPMI_TIMING0_DATA_HOLD. This AC timing depends on these registers settings. In the table, AS/DS/DH represents each of these settings.

2 AS minimum value can be 0, while DS/DH minimum value is 1.

3 T = tCK (GPMI clock period) -0.075ns (half of maximum p-p jitter).

4 CE_DELAY represents HW_GPMI_TIMING2[CE_DELAY]. NF18 is met automatically by the design. Read/Write operation is started with enough time of ALE/CLE assertion to low level.

5 PRE_DELAY+1) ≥ (AS+DS)

6 Shown in Figure 30.

7 Shown in Figure 31.

Figure 32 shows the timing diagram of NAND_DQS/NAND_DATAxx read valid window. For DDR Toggle mode, the typical value of tDQSQ is 1.4 ns (max) and 1.4 ns (max) for tQHS at 133 MB/s. GPMI will sample NAND_DATA[7:0] at both rising and falling edge of a delayed NAND_DQS signal, which is provided by an internal DPLL. The delay value of this register can be controlled by GPMI register GPMI_READ_DDR_DLL_CTRL.SLV_DLY_TARGET (see the GPMI chapter of the i.MX 6Dual/6Quad reference manual (IMX6DQRM)). Generally, the typical delay value is equal to 0x7 which means 1/4 clock cycle delay expected. However, if the board delay is large enough and cannot be ignored, the delay value should be made larger to compensate the board delay.

4.12 External Peripheral Interface Parameters

The following subsections provide information on external peripheral interfaces.

4.12.1 AUDMUX Timing Parameters

The AUDMUX provides a programmable interconnect logic for voice, audio, and data routing between internal serial interfaces (SSIs) and external serial interfaces (audio and voice codecs). The AC timing of AUDMUX external pins is governed by the SSI module. For more information, see the respective SSI electrical specifications found within this document.

4.12.2 ECSPI Timing Parameters

This section describes the timing parameters of the ECSPI block. The ECSPI has separate timing parameters for master and slave modes.

Table 50. SD/eMMC4.3 Interface Timing Specification (continued)

ID	Parameter	Symbols	Min	Max	Unit
eSDHC Input/Card Outputs SD_CMD, SD_DATAx (Reference to SDx_CLK)					
SD7	eSDHC Input Setup Time	t_{ISU}	2.5	—	ns
SD8	eSDHC Input Hold Time[4]	t_{IH}	1.5	—	ns

1 In low speed mode, card clock must be lower than 400 kHz, voltage ranges from 2.7 to 3.6 V.

2 In normal (full) speed mode for SD/SDIO card, clock frequency can be any value between 0—25 MHz. In high-speed mode, clock frequency can be any value between 0—50 MHz.

3 In normal (full) speed mode for MMC card, clock frequency can be any value between 0—20 MHz. In high-speed mode, clock frequency can be any value between 0—52 MHz.

4 To satisfy hold timing, the delay difference between clock input and cmd/data input must not exceed 2 ns.

4.12.4.2 eMMC4.4/4.41 (Dual Data Rate) eSDHCv3 AC Timing

Figure 40 depicts the timing of eMMC4.4/4.41. Table 51 lists the eMMC4.4/4.41 timing characteristics. Be aware that only SDx_DATAx is sampled on both edges of the clock (not applicable to SD_CMD).

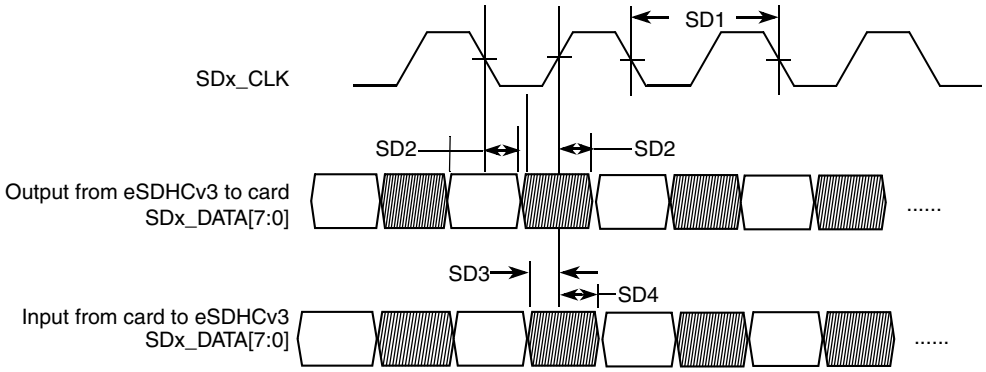


Figure 40. eMMC4.4/4.41 Timing

Table 51. eMMC4.4/4.41 Interface Timing Specification

ID	Parameter	Symbols	Min	Max	Unit
Card Input Clock[1]					
SD1	Clock Frequency (EMMC4.4 DDR)	f_{PP}	0	52	MHz
SD1	Clock Frequency (SD3.0 DDR)	f_{PP}	0	50	MHz
uSDHC Output / Card Inputs SD_CMD, SD_DATAx (Reference to SD_CLK)					
SD2	uSDHC Output Delay	t_{OD}	2.5	7.1	ns
uSDHC Input / Card Outputs SD_CMD, SD_DATAx (Reference to SD_CLK)					
SD3	uSDHC Input Setup Time	t_{ISU}	1.7	—	ns
SD4	uSDHC Input Hold Time	t_{IH}	1.5	—	ns

1 Clock duty cycle will be in the range of 47% to 53%.

Table 55. MII Asynchronous Inputs Signal Timing

ID	Characteristic	Min	Max	Unit
M9[1]	ENET_CRS to ENET_COL minimum pulse width	1.5	—	ENET_TX_CLK period

[1] ENET_COL has the same timing in 10-Mbit 7-wire interface mode.

4.12.5.1.4 MII Serial Management Channel Timing (ENET_MDIO and ENET_MDC)

The MDC frequency is designed to be equal to or less than 2.5 MHz to be compatible with the IEEE 802.3 MII specification. However the ENET can function correctly with a maximum MDC frequency of 15 MHz.

Figure 45 shows MII asynchronous input timings. Table 56 describes the timing parameters (M10–M15) shown in the figure.

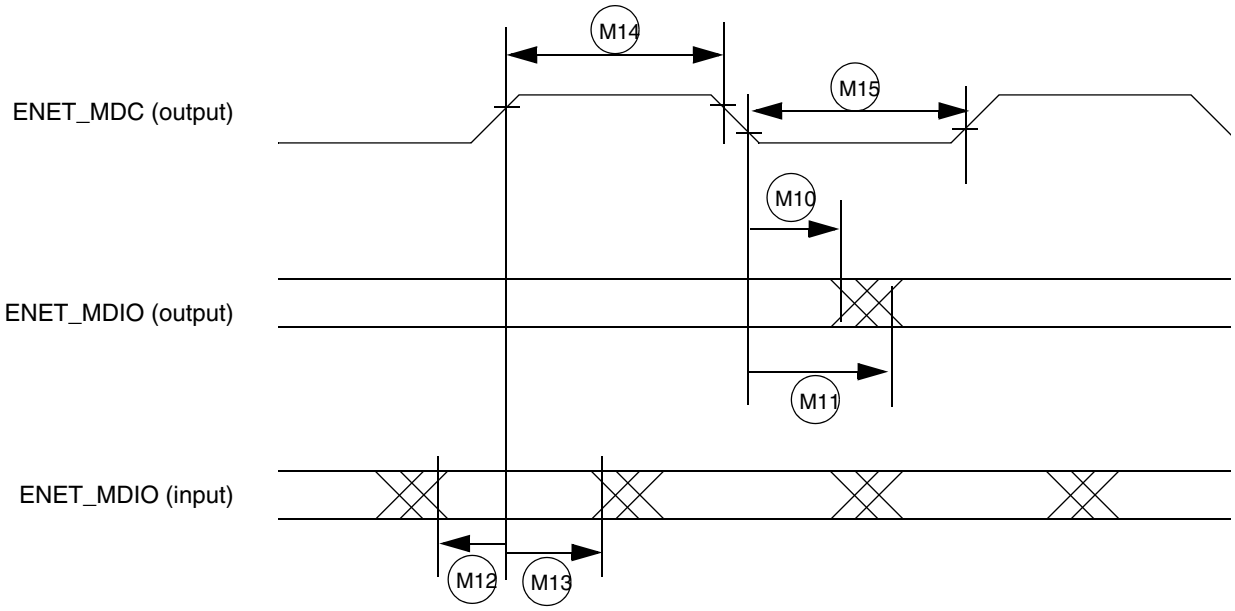


Figure 45. MII Serial Management Channel Timing Diagram

Table 56. MII Serial Management Channel Timing

ID	Characteristic	Min	Max	Unit
M10	ENET_MDC falling edge to ENET_MDIO output invalid (minimum propagation delay)	0	—	ns
M11	ENET_MDC falling edge to ENET_MDIO output valid (maximum propagation delay)	—	5	ns
M12	ENET_MDIO (input) to ENET_MDC rising edge setup	18	—	ns
M13	ENET_MDIO (input) to ENET_MDC rising edge hold	0	—	ns
M14	ENET_MDC pulse width high	40%	60%	ENET_MDC period
M15	ENET_MDC pulse width low	40%	60%	ENET_MDC period

stops receiving data from the stream. For the next line, the IPU2_CSIx_HSYNC timing repeats. For the next frame, the IPU2_CSIx_VSYNC timing repeats.

4.12.10.2.3 Non-Gated Clock Mode

The timing is the same as the gated-clock mode (described in Section 4.12.10.2.2, "Gated Clock Mode,") except for the IPU2_CSIx_HSYNC signal, which is not used (see Figure 60). All incoming pixel clocks are valid and cause data to be latched into the input FIFO. The IPU2_CSIx_PIX_CLK signal is inactive (states low) until valid data is going to be transmitted over the bus.

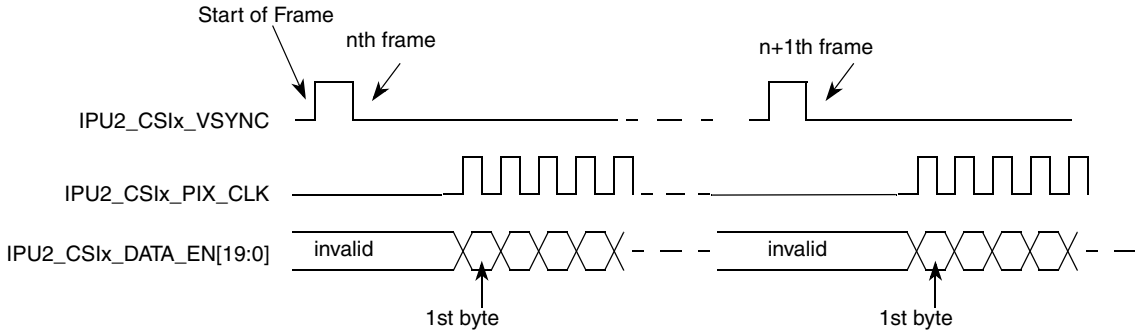


Figure 60. Non-Gated Clock Mode Timing Diagram

The timing described in Figure 60 is that of a typical sensor. Some other sensors may have a slightly different timing. The CSI can be programmed to support rising/falling-edge triggered IPU2_CSIx_VSYNC; active-high/low IPU2_CSIx_HSYNC; and rising/falling-edge triggered IPU2_CSIx_PIX_CLK.

Table 69. Electrical and Timing Information (continued)

Symbol	Parameters	Test Conditions	Min	Typ	Max	Unit
t_{CDC}	DDR CLK duty cycle	$t_{CDC} = t_{CPH} / P_{DDRCLK}$	—	50	—	%
t_{CPH}	DDR CLK high time	—	—	1	—	UI
t_{CPL}	DDR CLK low time	—	—	1	—	UI
—	DDR CLK / DATA Jitter	—	—	75	—	ps pk-pk
$t_{SKEW[PN]}$	Intra-Pair (Pulse) skew	—	—	0.075	—	UI
$t_{SKEW[TX]}$	Data to Clock Skew	—	0.350	—	0.650	UI
t_r	Differential output signal rise time	20% to 80%, RL = 50 Ω	150	—	0.3UI	ps
t_f	Differential output signal fall time	20% to 80%, RL = 50 Ω	150	—	0.3UI	ps
$\Delta V_{CMTX(HF)}$	Common level variation above 450 MHz	80 Ω<= RL< = 125 Ω	—	—	15	mV_{rms}
$\Delta V_{CMTX(LF)}$	Common level variation between 50 MHz and 450 MHz	80 Ω<= RL< = 125 Ω	—	—	25	mV_p
LP Line Drivers AC Specifications						
t_{rlp}, t_{flp}	Single ended output rise/fall time	15% to 85%, C_L<70 pF	—	—	25	ns
t_{reo}	—	30% to 85%, C_L<70 pF	—	—	35	ns
$\delta V/\delta t_{SR}$	Signal slew rate	15% to 85%, C_L<70 pF	—	—	120	mV/ns
C_L	Load capacitance	—	0	—	70	pF
HS Line Receiver AC Specifications						
$t_{SETUP[RX]}$	Data to Clock Receiver Setup time	—	0.15	—	—	UI
$t_{HOLD[RX]}$	Clock to Data Receiver Hold time	—	0.15	—	—	UI
$\Delta V_{CMRX(HF)}$	Common mode interference beyond 450 MHz	—	—	—	200	mVpp
$\Delta V_{CMRX(LF)}$	Common mode interference between 50 MHz and 450 MHz	—	-50	—	50	mVpp
C_{CM}	Common mode termination	—	—	—	60	pF
LP Line Receiver AC Specifications						
e_{SPIKE}	Input pulse rejection	—	—	—	300	Vps
T_{MIN}	Minimum pulse response	—	50	—	—	ns
V_{INT}	Pk-to-Pk interference voltage	—	—	—	400	mV
f_{INT}	Interference frequency	—	450	—	—	MHz
Model Parameters used for Driver Load switching performance evaluation						
C_{PAD}	Equivalent Single ended I/O PAD capacitance.	—	—	—	1	pF
C_{PIN}	Equivalent Single ended Package + PCB capacitance.	—	—	—	2	pF

Table 75. MLB 6-Pin Interface Timing Parameters

Parameter	Symbol	Min	Max	Unit	Comment
Cycle-to-cycle system jitter	t_{jitter}	—	600	ps	—
Transmitter MLB_SIG_P/_N (MLB_DATA_P/_N) output valid from transition of MLB_CLK_P/_N (low-to-high)[1]	t_{delay}	0.6	1.3	ns	—
Disable turnaround time from transition of MLB_CLK_P/_N (low-to-high)	t_{phz}	0.6	3.5	ns	—
Enable turnaround time from transition of MLB_CLK_P/_N (low-to-high)	t_{plz}	0.6	5.6	ns	—
MLB_SIG_P/_N (MLB_DATA_P/_N) valid to transition of MLB_CLK_P/_N (low-to-high)	t_{su}	0.05	—	ns	—
MLB_SIG_P/_N (MLB_DATA_P/_N) hold from transition of MLB_CLK_P/_N (low-to-high)[2]	t_{hd}	0.6	—	ns	—

1 t_{delay}, t_{phz}, t_{plz}, t_{su}, and t_{hd} may also be referenced from a low-to-high transition of the recovered clock for 2:1 and 4:1 recovered-to-external clock ratios.

2 The transmitting device must ensure valid data on MLB_SIG_P/_N (MLB_DATA_P/_N) for at least $t_{hd(min)}$ following the rising edge of MLBCP/N; receivers must latch MLB_SIG_P/_N (MLB_DATA_P/_N) data within $t_{hd(min)}$ of the rising edge of MLB_CLK_P/_N.

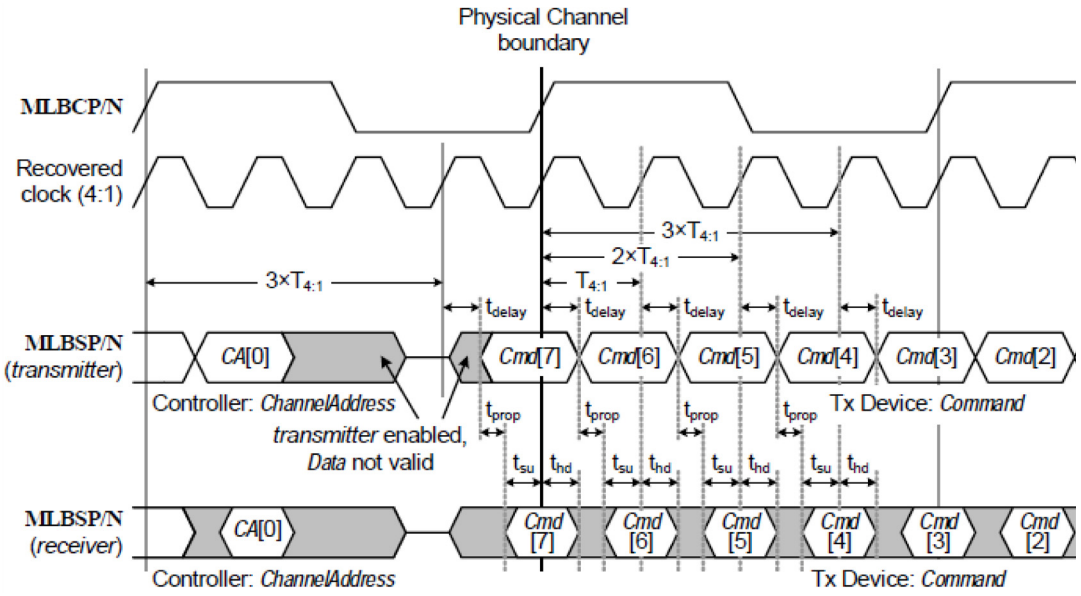


Figure 82. MLB 6-Pin Delay, Setup, and Hold Times

4.12.15 PCIe PHY Parameters

The PCIe interface complies with PCIe specification Gen2 x1 lane and supports the PCI Express 1.1/2.0 standard.

Table 85. SSI Receiver Timing with External Clock

ID	Parameter	Min	Max	Unit
External Clock Operation				
SS22	AUDx_TXC/AUDx_RXC clock period	81.4	—	ns
SS23	AUDx_TXC/AUDx_RXC clock high period	36	—	ns
SS24	AUDx_TXC/AUDx_RXC clock rise time	—	6.0	ns
SS25	AUDx_TXC/AUDx_RXC clock low period	36	—	ns
SS26	AUDx_TXC/AUDx_RXC clock fall time	—	6.0	ns
SS28	AUDx_RXC high to AUDx_TXFS (bl) high	–10	15.0	ns
SS30	AUDx_RXC high to AUDx_TXFS (bl) low	10	—	ns
SS32	AUDx_RXC high to AUDx_TXFS (wl) high	–10	15.0	ns
SS34	AUDx_RXC high to AUDx_TXFS (wl) low	10	—	ns
SS35	AUDx_TXC/AUDx_RXC External AUDx_TXFS rise time	—	6.0	ns
SS36	AUDx_TXC/AUDx_RXC External AUDx_TXFS fall time	—	6.0	ns
SS40	AUDx_RXD setup time before AUDx_RXC low	10	—	ns
SS41	AUDx_RXD hold time after AUDx_RXC low	2	—	ns

NOTE

- All the timings for the SSI are given for a non-inverted serial clock polarity (TSCKP/RSCKP = 0) and a non-inverted frame sync (TFSI/RFSI = 0). If the polarity of the clock and/or the frame sync have been inverted, all the timing remains valid by inverting the clock signal AUDx_TXC/AUDx_RXC and/or the frame sync AUDx_TXFS/AUDx_RXFS shown in the tables and in the figures.
- All timings are on Audiomux Pads when SSI is being used for data transfer.
- AUDx_TXC and AUDx_RXC refer to the Transmit and Receive sections of the SSI.
- The terms, WL and BL, refer to Word Length (WL) and Bit Length(BL).
- For internal Frame Sync operation using external clock, the frame sync timing is same as that of transmit data (for example, during AC97 mode of operation).

Table 93. Fuses and Associated Pins Used for Boot (continued)

Pin	Direction at Reset	eFuse Name
EIM_A18	Input	BOOT_CFG3[2]
EIM_A19	Input	BOOT_CFG3[3]
EIM_A20	Input	BOOT_CFG3[4]
EIM_A21	Input	BOOT_CFG3[5]
EIM_A22	Input	BOOT_CFG3[6]
EIM_A23	Input	BOOT_CFG3[7]
EIM_A24	Input	BOOT_CFG4[0]
EIM_WAIT	Input	BOOT_CFG4[1]
EIM_LBA	Input	BOOT_CFG4[2]
EIM_EB0	Input	BOOT_CFG4[3]
EIM_EB1	Input	BOOT_CFG4[4]
EIM_RW	Input	BOOT_CFG4[5]
EIM_EB2	Input	BOOT_CFG4[6]
EIM_EB3	Input	BOOT_CFG4[7]

[1] Pin value overrides fuse settings for BT_FUSE_SEL = '0'. Signal Configuration as Fuse Override Input at Power Up. These are special I/O lines that control the boot up configuration during product development. In production, the boot configuration can be controlled by fuses.

5.2 Boot Devices Interfaces Allocation

Table 94 lists the interfaces that can be used by the boot process in accordance with the specific boot mode configuration. The table also describes the interface's specific modes and IOMUXC allocation, which are configured during boot when appropriate.

Table 94. Interfaces Allocation During Boot

Interface	IP Instance	Allocated Pads During Boot	Comment
SPI	ECSPI-1	EIM_D17, EIM_D18, EIM_D16, EIM_EB2, EIM_D19, EIM_D24, EIM_D25	—
SPI	ECSPI-2	CSI0_DAT10, CSI0_DAT9, CSI0_DAT8, CSI0_DAT11, EIM_LBA, EIM_D24, EIM_D25	—
SPI	ECSPI-3	DISP0_DAT2, DISP0_DAT1, DISP0_DAT0, DISP0_DAT3, DISP0_DAT4, DISP0_DAT5, DISP0_DAT6	—
SPI	ECSPI-4	EIM_D22, EIM_D28, EIM_D21, EIM_D20, EIM_A25, EIM_D24, EIM_D25	—
SPI	ECSPI-5	SD1_DAT0, SD1_CMD, SD1_CLK, SD1_DAT1, SD1_DAT2, SD1_DAT3, SD2_DAT3	—
EIM	EIM	EIM_DA[15:0], EIM_D[31:16], CSI0_DAT[19:4], CSI0_DATA_EN, CSI0_VSYNC	Used for NOR, OneNAND boot Only CS0 is supported